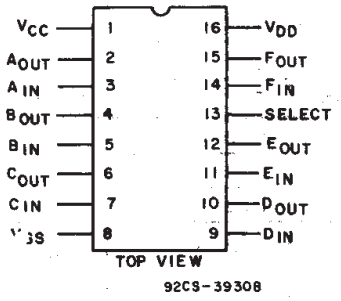
CD4504B Types



TERMINAL ASSIGNMENT

CMOS Hex Voltage-Level Shifter for TTL-to-CMOS or CMOS-to-CMOS Operation

High-Voltage Types (20-Volt Rating)

Features:

- *Independence of power-supply sequence considerations-V_{CC} can exceed V_{DD}; input signals can exceed both V_{CC} and V_{DD}*
- *Up and down level-shifting capability*
- *Shiftable input threshold for either CMOS or TTL compatibility*
- *Standardized symmetrical output characteristics*
- *100% tested for quiescent current @ 20 V*
- *Maximum input current of 1 µA at 18 V over full package-temperature range; 100 nA at 18 V and 25° C*
- *5 V, 10 V, and 15 V parametric ratings*
- *Meets all requirements of JEDEC Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"*

■ CD4504B hex voltage level-shifter consists of six circuits which shift input signals from the V_{CC} logic level to the V_{DD} logic level. To shift TTL signals to CMOS logic levels, the SELECT input is at the V_{CC} HIGH logic state. When the SELECT input is at a LOW logic state, each circuit translates signals from one CMOS level to another.

The CD4504B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, and MT suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

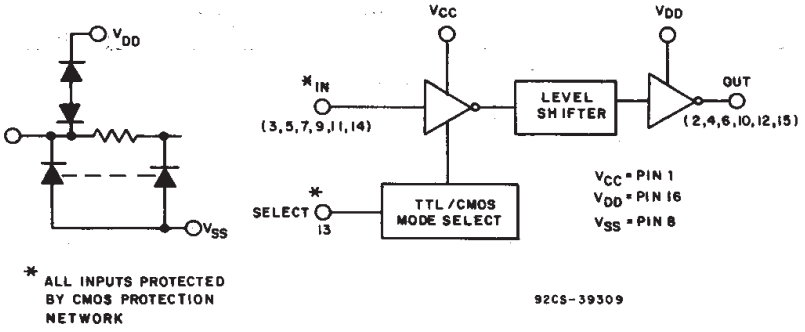


Fig. 1 - Functional diagram for CD4504B.

MAXIMUM RATINGS, *Absolute-Maximum Values:*

DC SUPPLY-VOLTAGE RANGE, (V_{DD})
(Voltages referenced to V_{SS} Terminal) ..... -0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS ..... -0.5V to V_{CC} +0.5V
DC INPUT CURRENT, ANY ONE INPUT ..... ±10mA
POWER DISSIPATION PER PACKAGE (P_D):
For T_A = -55°C to +100°C 500mW
For T_A = +100°C to +125°C ..... Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T_A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
OPERATING-TEMPERATURE RANGE (T_A) ..... -55°C to +125°C
STORAGE TEMPERATURE RANGE (T_{stg}) ..... -65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max ..... +265°C

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V_{GEN}

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC		CONDITIONS V_O (V)	V_{IN} (V)	V_{CC} (V)	V_{DD} (V)	LIMITS AT INDICATED TEMPERATURES (°C) -55	-40	+85	+125	+25 MIN	+25 TYP	+25 MAX	UNITS
Quiescent Device Current, I_{DD} Max and I_{CC} in CMOS-CMOS Mode		—	0, 5	5	5	1.5	1.5	1.5	1.5	—	0.02	1.5	mA
		—	0, 10	5	10	2	2	2	2	—	0.02	2	
		—	0, 15	5	15	4	4	120	120	—	0.02	4	μA
		—	0, 20	5	20	20	20	600	600	—	0.04	20	
Quiescent Device Current, I_{CC} Max TTL-CMOS Mode		—	0, 5	5	5	5	5	6	6	—	2.5	5	mA
		—	0, 10	5	10	5	5	6	6	—	2.5	5	
		—	0, 15	5	15	5	5	6	6	—	2.5	5	
Output Low (Sink) Current, I_{OL} Min		0.4	0.5	—	5	0.64	0.61	0.42	0.36	0.51	1	—	mA
		0.5	0, 10	—	10	1.6	1.5	1.1	0.9	1.3	2.6	—	
		1.5	0, 15	—	15	4.2	4	2.8	2.4	3.4	6.8	—	
Output High (Source) Current, I_{OH} Min		4.6	0, 5	—	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	
		2.5	0, 5	—	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—	
		9.5	0, 10	—	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
		13.5	0, 15	—	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—	
Output Voltage: Low-Level, V_{OL} Max		—	0, 5	—	5	0.05				—	0	0.05	V
		—	0, 10	—	10	0.05				—	0	0.05	
		—	0, 15	—	15	0.05				—	0	0.05	
Output Voltage: High-Level, V_{OH} Min		—	0, 5	—	5	4.95				4.95	5	—	
		—	0, 10	—	10	9.95				9.95	10	—	
		—	0, 15	—	15	14.95				14.95	15	—	
Input Low Voltage, V_{IL} Max Note 1	TTL-CMOS	1	—	5	10	0.8				—	—	0.8	
	TTL-CMOS	1	—	5	15	0.8				—	—	0.8	
	CMOS-CMOS	1	—	5	10	1.5				—	—	1.5	
	CMOS-CMOS	1.5	—	5	15	1.5				—	—	1.5	
	CMOS-CMOS	1.5	—	10	15	3				—	—	3	
Input High Voltage, V_{IH} Min Note 1	TTL-CMOS	9	—	5	10	2				2	—	—	
	TTL-CMOS	13.5	—	5	15	2				2	—	—	
	CMOS-CMOS	9	—	5	10	3.5				3.5	—	—	
	CMOS-CMOS	13.5	—	5	15	3.5				3.5	—	—	
	CMOS-CMOS	13.5	—	10	15	7				7	—	—	
Input Current, I_{IN} Max		—	0, 18	—	18	±0.1	±0.1	±1	±1	—	$\pm 10^{-5}$	±0.1	μA

Note 1: Applies to the 6 input signals. For mode control (P13), only the CMOS-CMOS ratings apply.

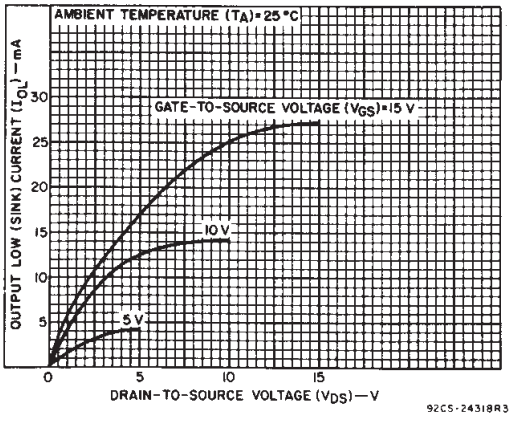


Fig. 2 - Typical output low (sink) current characteristics.

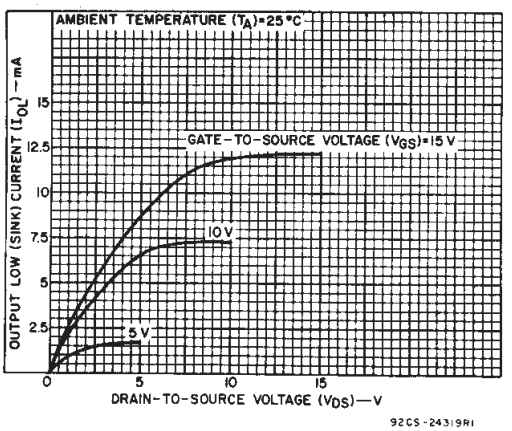


Fig. 3 - Minimum output low (sink) current characteristics.

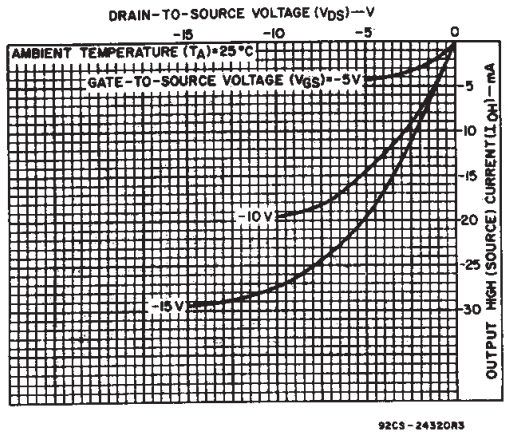


Fig. 4 - Typical output high (source) current characteristics.

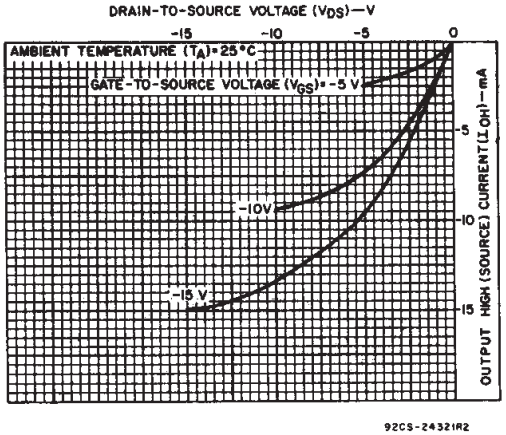


Fig. 5 - Minimum output high (source) current characteristics.

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V_{DD} (V)	LIMITS		UNITS
		Min.	Max.	
Supply-Voltage Range (For T_A = Full Package-Temperature Range)	—	5	18	V

DYNAMIC ELECTRICAL CHARACTERISTICS, At T_A = 25°C; Input t_r,t_f = 20 ns, C_L = 50 pF, R_L = 200 Ω

CHARACTERISTIC		SHIFTING MODE	VCC (V)	VDD (V)	LIMITS TYP.	LIMITS MAX.	UNITS
Propagation Delay: High-to Low,	t_{PHL}	TTL to CMOS $V_{DD} > V_{CC}$	5	10	140	280	ns
			5	15	140	280	
		CMOS to CMOS $V_{DD} > V_{CC}$	5	10	120	240	
			5	15	120	240	
			10	15	70	140	
		CMOS to CMOS $V_{CC} > V_{DD}$	10	5	275	550	
			15	5	275	550	
			15	10	70	140	
Low-to-High,	t_{PLH}	TTL to CMOS $V_{DD} > V_{CC}$	5	10	140	280	
			5	15	140	280	
		CMOS to CMOS $V_{DD} > V_{CC}$	5	10	120	240	
			5	15	120	240	
			10	15	70	140	
		CMOS to CMOS $V_{CC} > V_{DD}$	10	5	200	400	
			15	5	200	400	
			15	10	60	120	
Transition Time,	t_{THL},t_{TLH}	All Modes		5	100	200	
				10	50	100	
				15	40	80	
Input Capacitance,	C_{IN}	Any Input			5	7.5	pF

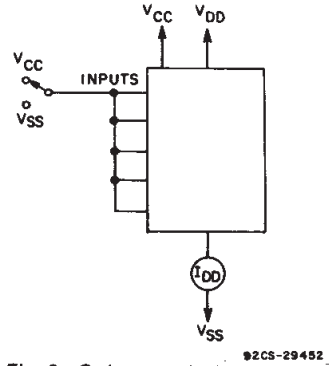


Fig. 6 - Quiescent device current.

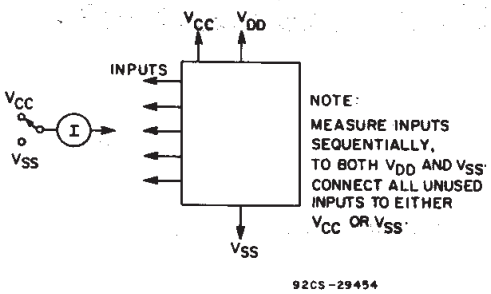


Fig. 7 - Input current.

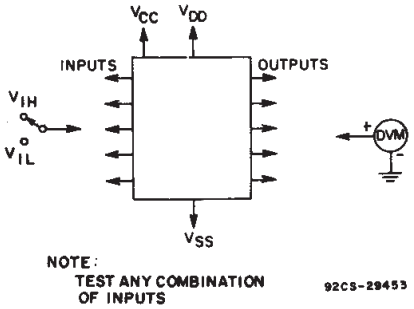


Fig. 8 - Input voltage.

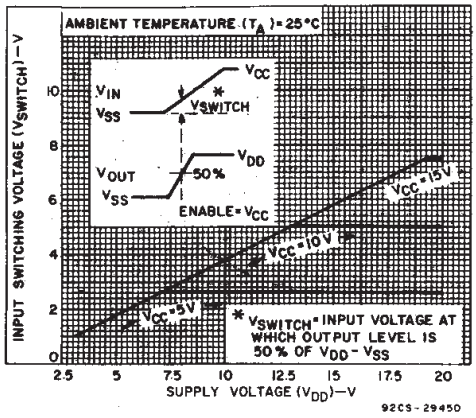


Fig. 9 - Typical input switching as a function of high-level supply voltage. (SELECT at V_{CC}-CMOS mode).

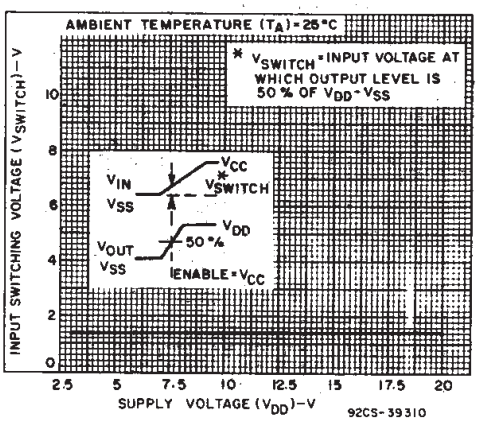


Fig. 10 - Typical input switching as a function of high-level supply voltage (SELECT at V_{SS}-TTL mode).

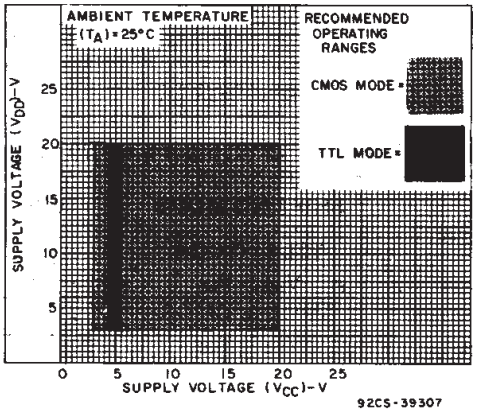
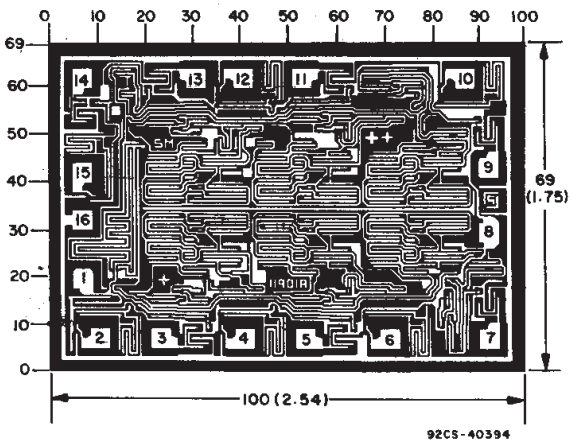


Fig. 11 - High-level supply voltage vs. low-level supply voltage.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

Dimensions and pad layout for CD4504BH.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CD4504BE	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4504BE
CD4504BE.A	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4504BE
CD4504BEE4	Active	Production	PDIP (N) | 16	25 | TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4504BE
CD4504BF3A	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4504BF3A
CD4504BF3A.A	Active	Production	CDIP (J) | 16	25 | TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4504BF3A
CD4504BM	Active	Production	SOIC (D) | 16	40 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BM.A	Active	Production	SOIC (D) | 16	40 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BM96	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BM96.A	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BM96E4	Active	Production	SOIC (D) | 16	2500 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BME4	Active	Production	SOIC (D) | 16	40 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BMG4	Active	Production	SOIC (D) | 16	40 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BMT	Active	Production	SOIC (D) | 16	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BMT.A	Active	Production	SOIC (D) | 16	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4504BM
CD4504BPW	Active	Production	TSSOP (PW) | 16	90 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B
CD4504BPW.A	Active	Production	TSSOP (PW) | 16	90 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B
CD4504BPWE4	Active	Production	TSSOP (PW) | 16	90 | TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B
CD4504BPWR	Active	Production	TSSOP (PW) | 16	2000 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-55 to 125	CM504B
CD4504BPWR.A	Active	Production	TSSOP (PW) | 16	2000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM504B

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF CD4504B, CD4504B-MIL :

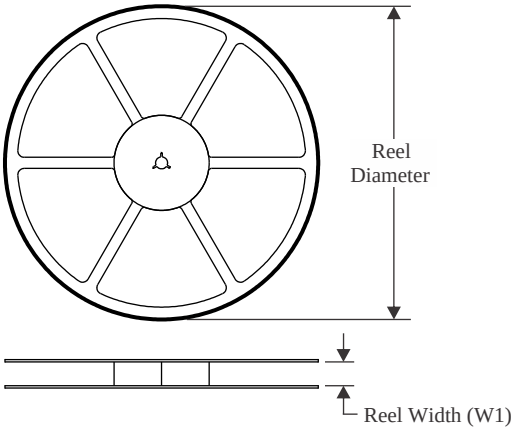
- Catalog : CD4504B
- Enhanced Product : CD4504B-EP, CD4504B-EP
- Military : CD4504B-MIL

NOTE: Qualified Version Definitions:

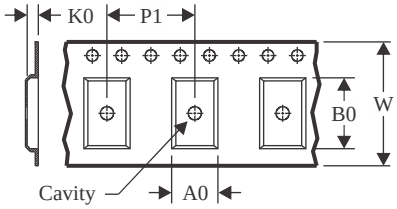
- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

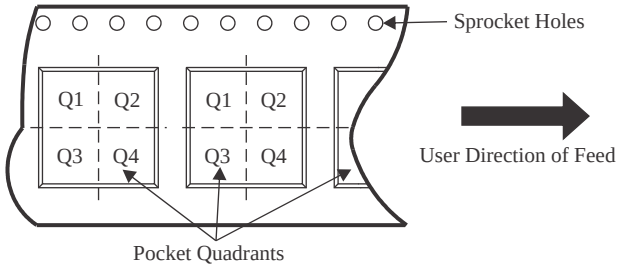


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

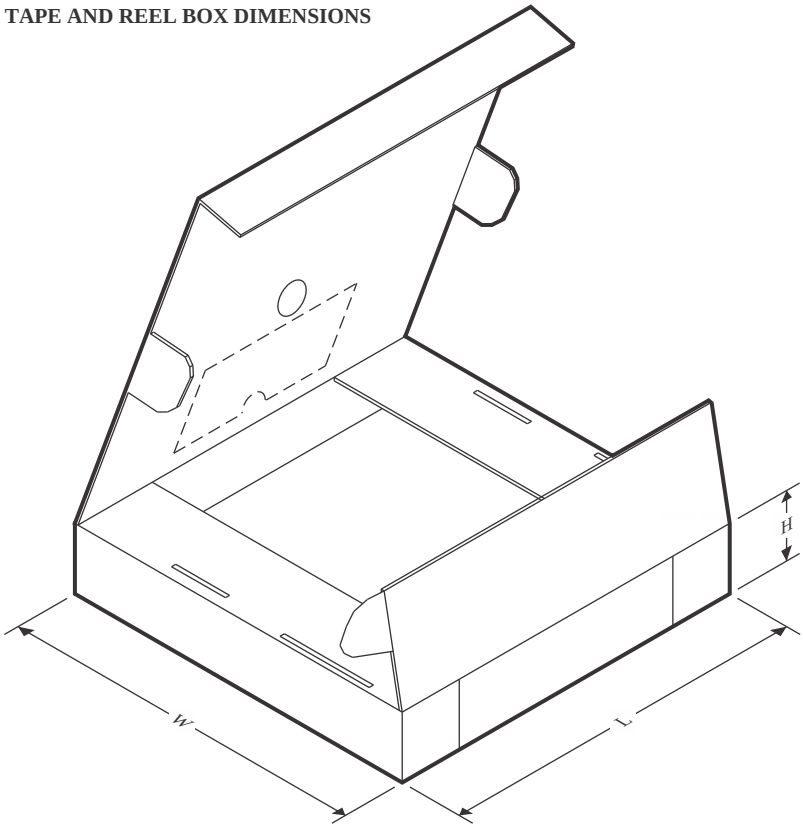
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4504BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4504BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4504BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

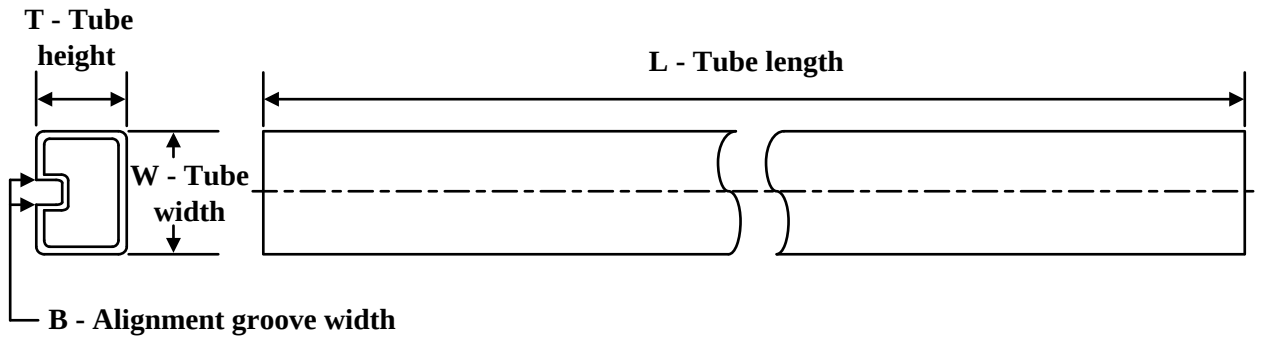
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4504BM96	SOIC	D	16	2500	353.0	353.0	32.0
CD4504BPWR	TSSOP	PW	16	2000	353.0	353.0	32.0
CD4504BPWR	TSSOP	PW	16	2000	356.0	356.0	35.0

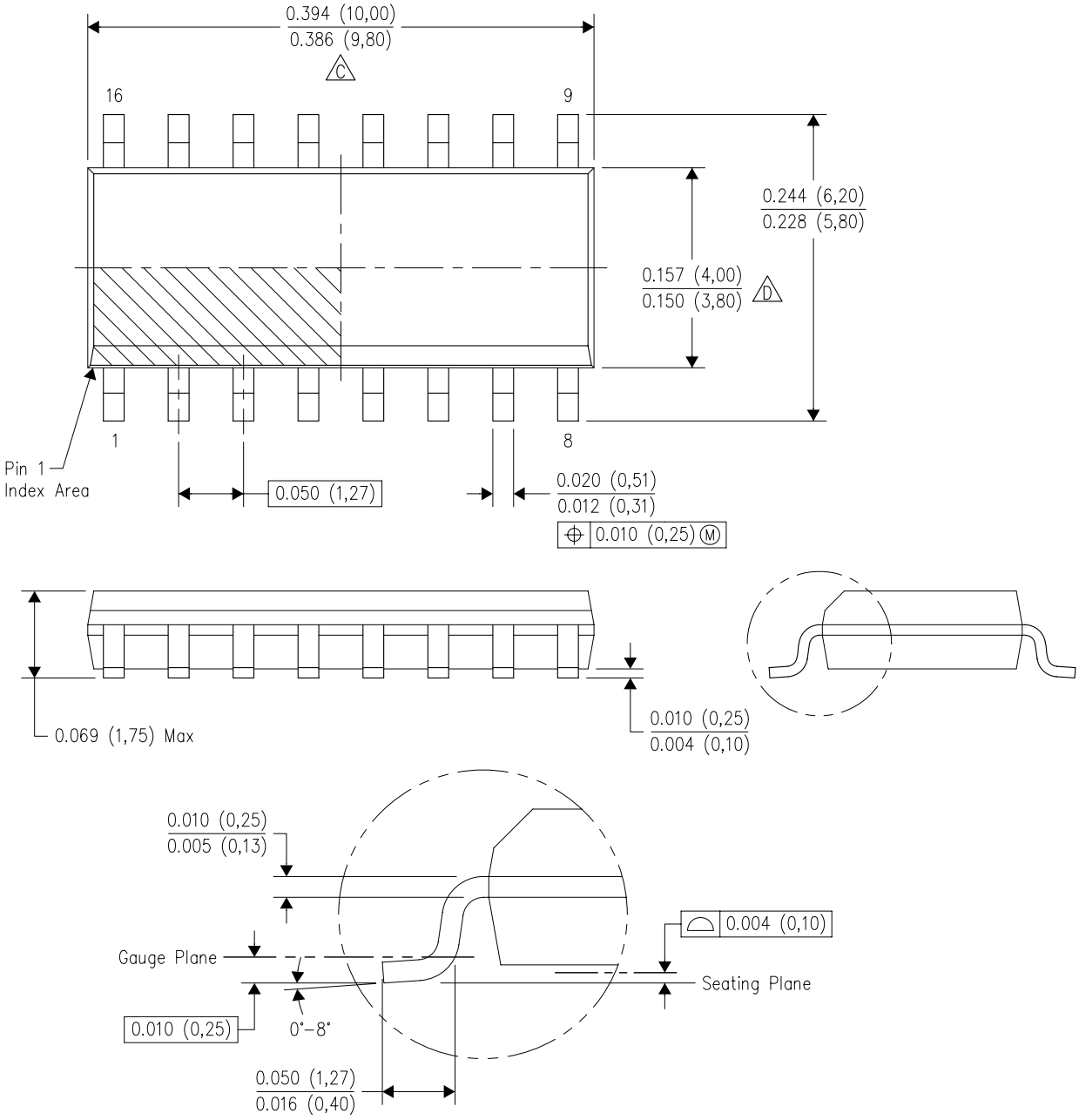
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4504BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BE.A	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BE.A	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4504BM	D	SOIC	16	40	507	8	3940	4.32
CD4504BM.A	D	SOIC	16	40	507	8	3940	4.32
CD4504BME4	D	SOIC	16	40	507	8	3940	4.32
CD4504BMG4	D	SOIC	16	40	507	8	3940	4.32
CD4504BPW	PW	TSSOP	16	90	530	10.2	3600	3.5
CD4504BPW.A	PW	TSSOP	16	90	530	10.2	3600	3.5
CD4504BPWE4	PW	TSSOP	16	90	530	10.2	3600	3.5

D (R–PDSO–G16) PLASTIC SMALL OUTLINE

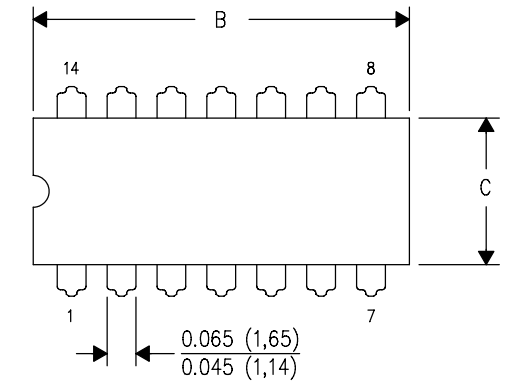


NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

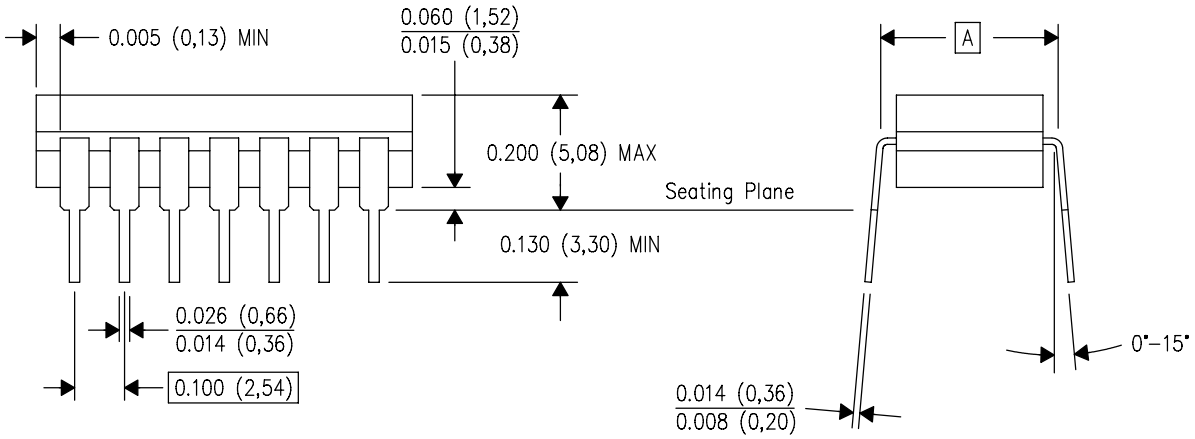
J (R–GDIP–T**)

14 LEADS SHOWN

CERAMIC DUAL IN–LINE PACKAGE



DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



4040083/F 03/03

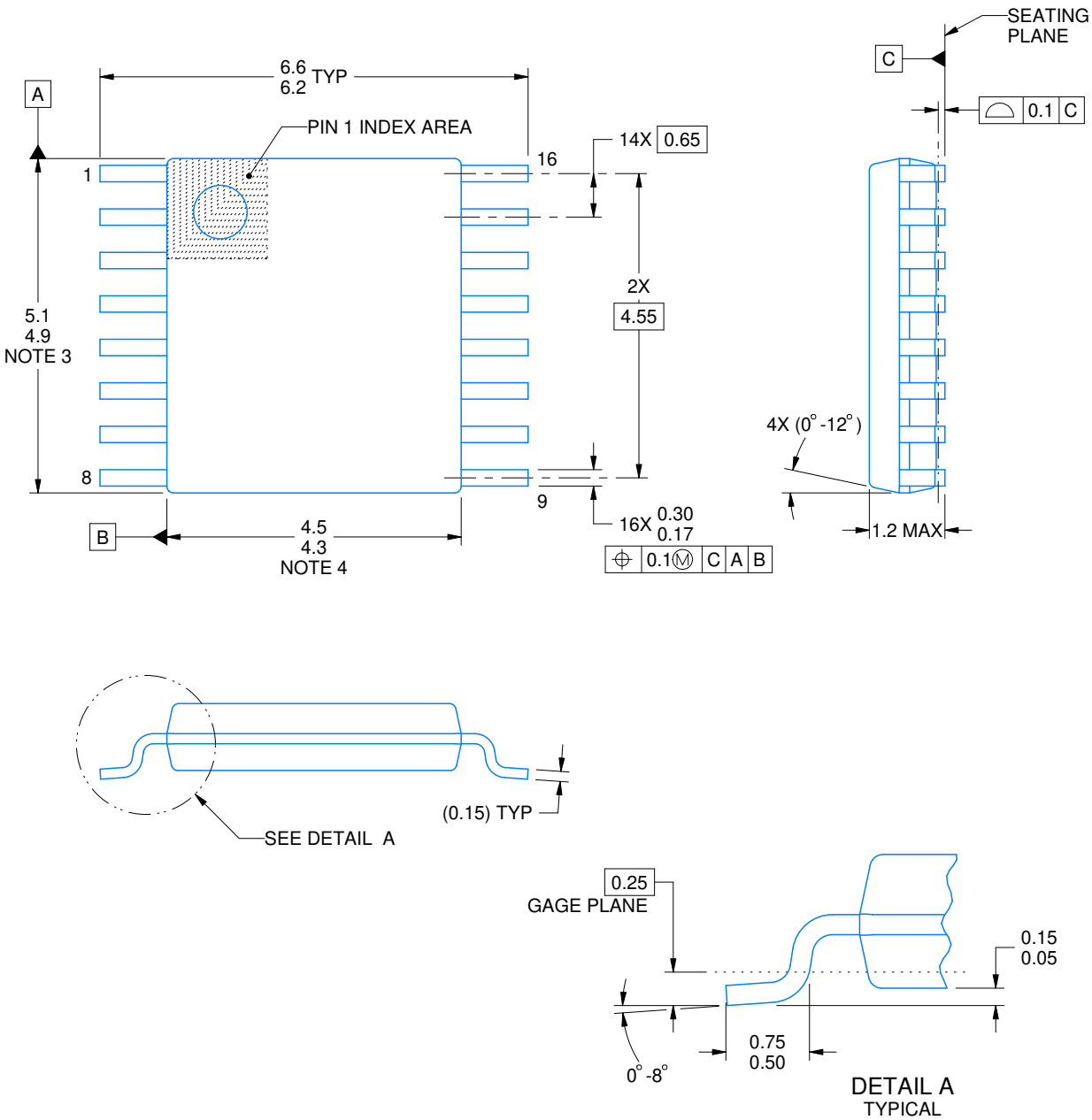
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package is hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
E. Falls within MIL STD 1835 GDIP1–T14, GDIP1–T16, GDIP1–T18 and GDIP1–T20.

PACKAGE OUTLINE

PW0016A

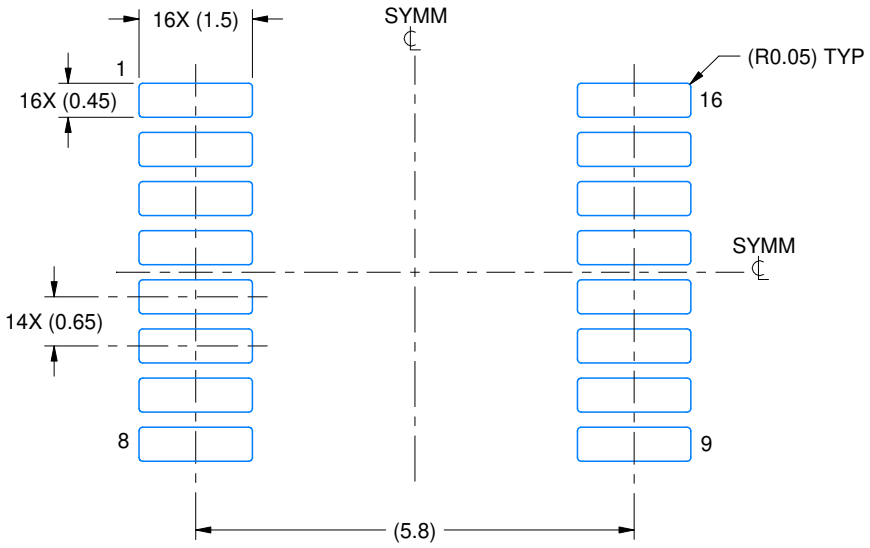
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

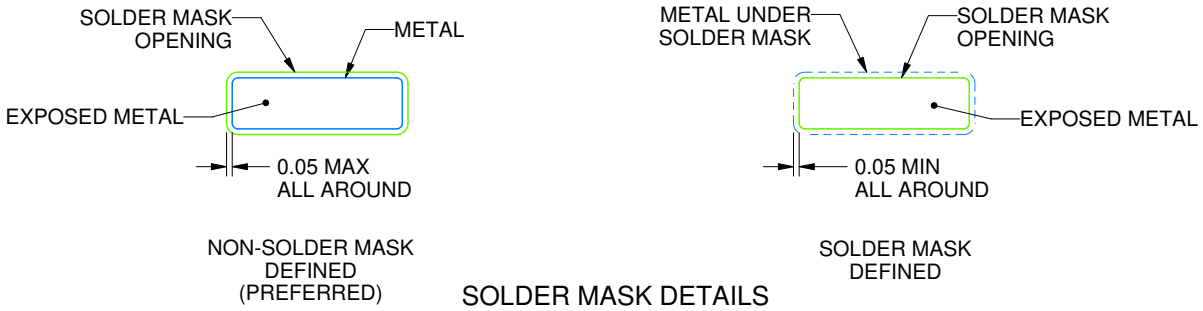


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

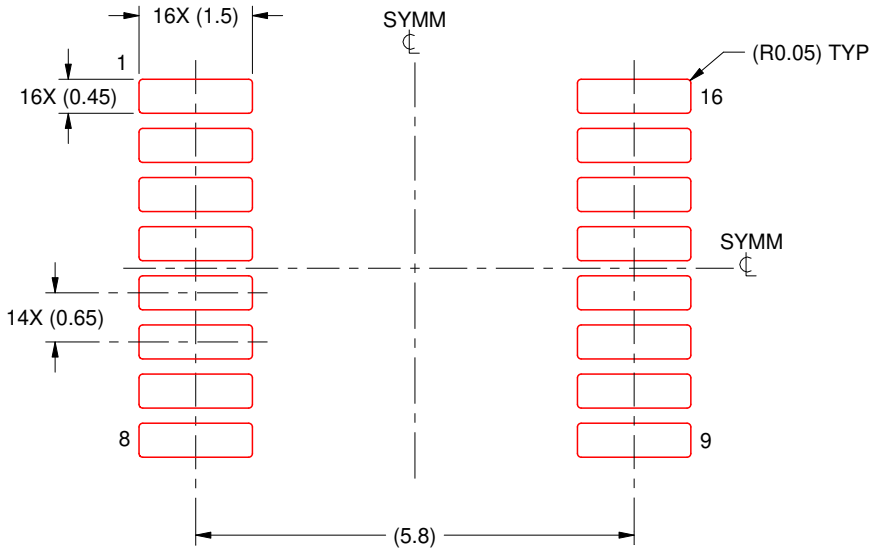


SOLDER MASK DETAILS

4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

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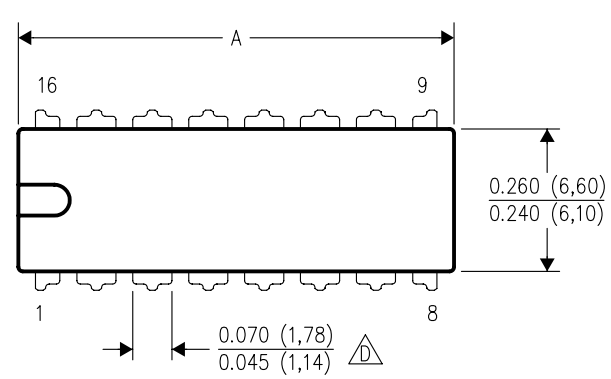
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

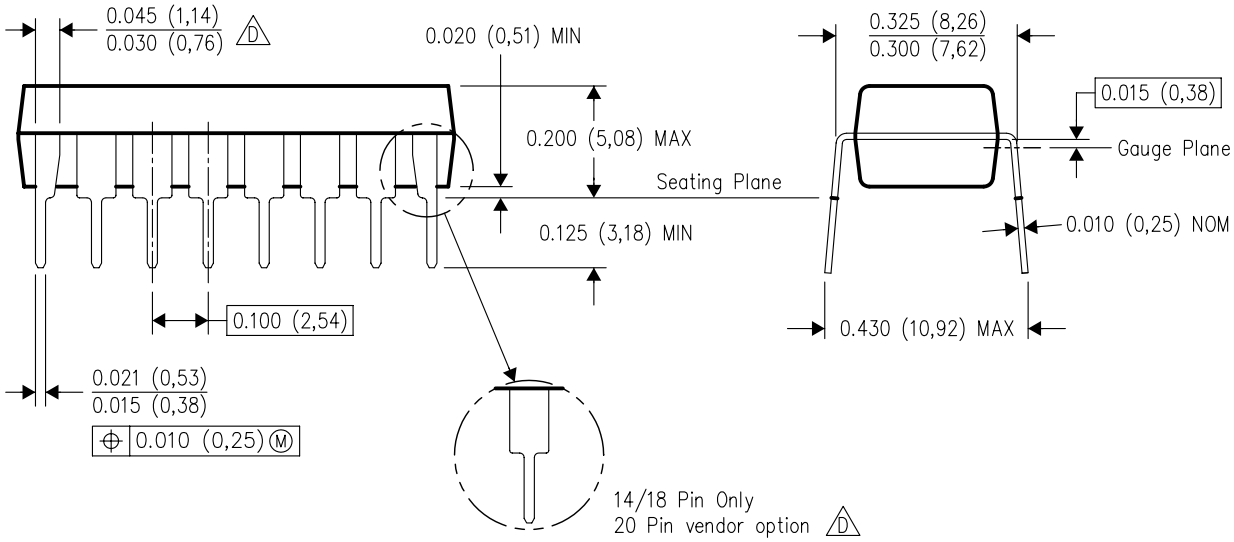
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN



DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



4040049/E 12/2002

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

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